

# Low Noise, High PSRR Replica Voltage Regulator

### 1.Features

Power Supply : 1.8 V Output voltage : 1.2 V Quiescent current: 7.3 mA Maximum current: 61 mA Reference Voltage: 1.2 V PSRR: 56 dB @1 KHz 32 dB @1 MHz Noise @1KHz: -144 dBV/sqrt (Hz) (60 nV/sqrt (Hz)) Noise @1MHz: -178 dBV/sqrt (Hz) (1.2 nV/sqrt (Hz)) Bandwidth: 6.8 KHz Drop-out voltage: 16 uV (vdd18 :1.6 V - 1.8 V) Load regulation: -2.9 mV/mA lload from 0-60mA (-2 mV/mA lload close to 20mA) WakeUp Time <sup>(1)</sup>: 1.5 ns Area : 400 um x 140 um Process: 22FDX Metal Option: 19

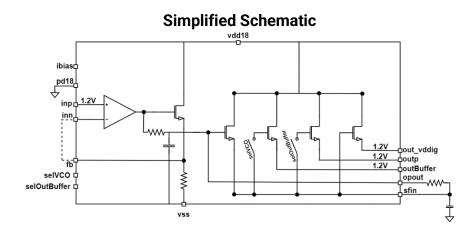
## 3.Description

The WEALDO18NI12SFN32M22G is a voltage regulator operating from 1.8 V. It provides three output voltages 1.2 V driving output load that sinks specific current. The first output voltage applies to the VCO, the second drives the OutBuffer and the last one drives the digital circuitry.

(1) Cload=10 pF

## 2.Applications

VCOs, PLLs, Power Supply Noise sensitive circuits. Circuits with low line regulation requirements





## 4. PinOut Description

Pinout	Purpose <sup>(1)</sup>	Description
vdd18	PS	1.8 V Input Supply Voltage
VSS	GND	Power Ground
ibias	AIO	25 uA Bias Supply
pd18	DI	Power Down pin. Drive pd18 to vss to turn on the regulator. Drive pd18 to vdd18 to put the voltage regulator (LDO) into shutdown mode.
Vrefin	I	1.2 V Reference Voltage
inp	I	Positive Opamp Input
inn	I	Negative Opamp Input
fb	10	Feedback
selVCO	I	Selects the outp
selOutBuffer	I	Selects the outBuffer
outp	0	1.2 Output Voltage
outBuffer	0	1.2 Output Voltage
out_vddig	0	1.2 Output Voltage

(1) I=Input, O=Output, IO=Inpout,Output ,PS=Power Supply, DI= Digital Input, AIO=Analog Input Output



#### Availability

GF 22FDX, Metal Option 19

#### Deliverables

GDSII, Database, SystemVerilog Models

## About weasic

**Weasic Microelectronics S.A.** designs, develops, and markets high quality complex analog and RF IP for the wired and the wireless communications industries, helping semiconductor and system companies to shrink the product design cycle. Weasic, silicon verified, IP is designed in the state-of-the-art CMOS and SiGe processes and can be easily ported and customized to serve the development of transceivers for 5G communications, Mobile Backhaul, RADAR sensors and 802.11.\* applications.

## Contact us

1 Alamanas str., 15125 Marousi, Greece



а

+30 210 6100770



info@weasic.com

weasic.com